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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	STM8
Core Size	8-Bit
Speed	24MHz
Connectivity	I²C, IrDA, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	52
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	1.5K x 8
RAM Size	6K x 8
Voltage - Supply (Vcc/Vdd)	2.95V ~ 5.5V
Data Converters	A/D 16x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm8s207r8t6tr

Asynchronous communication (UART mode)

- Full duplex communication - NRZ standard format (mark/space)
- Programmable transmit and receive baud rates up to 1 Mbit/s (f_{CPU}/16) and capable of following any standard baud rate regardless of the input frequency
- Separate enable bits for transmitter and receiver
- Two receiver wakeup modes:
  - Address bit (MSB)
  - Idle line (interrupt)
- Transmission error detection with interrupt generation
- Parity control

LIN master capability

- Emission: Generates 13-bit sync break frame
- Reception: Detects 11-bit break frame

LIN slave mode

- Autonomous header handling - one single interrupt per valid message header
- Automatic baud rate synchronization - maximum tolerated initial clock deviation ±15%
- Sync delimiter checking
- 11-bit LIN sync break detection - break detection always active
- Parity check on the LIN identifier field
- LIN error management
- Hot plugging support

4.14.3 SPI

- Maximum speed: 10 Mbit/s (f_{MASTER}/2) both for master and slave
- Full duplex synchronous transfers
- Simplex synchronous transfers on two lines with a possible bidirectional data line
- Master or slave operation - selectable by hardware or software
- CRC calculation
- 1 byte Tx and Rx buffer
- Slave/master selection input pin

Table 6. Pin description (continued)

Pin number					Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
LQFP80	LQFP64	LQFP48	LQFP44	LQFP32			floating	wpu	Ext. interrupt	High sink	Speed	OD	PP			
12	12	12	11	-	PA6/UART1_CK	I/O	**X**	X	X	HS	O3	X	X	**Port A6**	UART1 synchronous clock	
13	-	-	-	-	PH0	I/O	**X**	X		HS	O3	X	X	**Port H0**		
14	-	-	-	-	PH1	I/O	**X**	X		HS	O3	X	X	**Port H1**		
15	-	-	-	-	PH2	I/O	**X**	X			O1	X	X	**Port H2**		
16	-	-	-	-	PH3	I/O	**X**	X			O1	X	X	**Port H3**		
17	13	-	-	-	PF7/AIN15	I/O	**X**	X			O1	X	X	**Port F7**	Analog input 15	
18	14	-	-	-	PF6/AIN14	I/O	**X**	X			O1	X	X	**Port F6**	Analog input 14	
19	15	-	-	-	PF5/AIN13	I/O	**X**	X			O1	X	X	**Port F5**	Analog input 13	
20	16	-	-	8	PF4/AIN12	I/O	**X**	X			O1	X	X	**Port F4**	Analog input 12	
21	17	-	-	-	PF3/AIN11	I/O	**X**	X			O1	X	X	**Port F3**	Analog input 11	
22	18	-	-	-	V_{REF+}	S								ADC positive reference voltage		
23	19	13	12	9	V_{DDA}	S								Analog power supply		
24	20	14	13	10	V_{SSA}	S								Analog ground		
25	21	-	-	-	V_{REF-}	S								ADC negative reference voltage		
26	22	-	-	-	PF0/AIN10	I/O	**X**	X			O1	X	X	**Port F0**	Analog input 10	
27	23	15	14	-	PB7/AIN7	I/O	**X**	X	X		O1	X	X	**Port B7**	Analog input 7	
28	24	16	15	-	PB6/AIN6	I/O	**X**	X	X		O1	X	X	**Port B6**	Analog input 6	
29	25	17	16	11	PB5/AIN5	I/O	**X**	X	X		O1	X	X	**Port B5**	Analog input 5	I^2C_SDA [AFR6]
30	26	18	17	12	PB4/AIN4	I/O	**X**	X	X		O1	X	X	**Port B4**	Analog input 4	I^2C_SCL [AFR6]

Table 9. General hardware register map

Address	Block	Register label	Register name	Reset status
0x00 5050 to 0x00 5059	Reserved area (10 bytes)			
0x00 505A	Flash	FLASH_CR1	Flash control register 1	0x00
0x00 505B		FLASH_CR2	Flash control register 2	0x00
0x00 505C		FLASH_NCR2	Flash complementary control register 2	0xFF
0x00 505D		FLASH _FPR	Flash protection register	0x00
0x00 505E		FLASH _NFPR	Flash complementary protection register	0xFF
0x00 505F		FLASH _IAPSR	Flash in-application programming status register	0x00
0x00 5060 to 0x00 5061	Reserved area (2 bytes)			
0x00 5062	Flash	FLASH _PUKR	Flash Program memory unprotection register	0x00
0x00 5063	Reserved area (1 byte)			
0x00 5064	Flash	FLASH _DUKR	Data EEPROM unprotection register	0x00
0x00 5065 to 0x00 509F	Reserved area (59 bytes)			
0x00 50A0	ITC	EXTI_CR1	External interrupt control register 1	0x00
0x00 50A1		EXTI_CR2	External interrupt control register 2	0x00
0x00 50A2 to 0x00 50B2	Reserved area (17 bytes)			
0x00 50B3	RST	RST_SR	Reset status register	0xXX(1)
0x00 50B4 to 0x00 50BF	Reserved area (12 bytes)			
0x00 50C0	CLK	CLK_ICKR	Internal clock control register	0x01
0x00 50C1		CLK_ECKR	External clock control register	0x00
0x00 50C2	Reserved area (1 byte)			
0x00 50C3	CLK	CLK_CMSR	Clock master status register	0xE1
0x00 50C4		CLK_SWR	Clock master switch register	0xE1
0x00 50C5		CLK_SWCR	Clock switch control register	0xXX
0x00 50C6		CLK_CKDIVR	Clock divider register	0x18
0x00 50C7		CLK_PCKENR1	Peripheral clock gating register 1	0xFF
0x00 50C8		CLK_CSSR	Clock security system register	0x00
0x00 50C9		CLK_CCOR	Configurable clock control register	0x00
0x00 50CA		CLK_PCKENR2	Peripheral clock gating register 2	0xFF
0x00 50CB		CLK_CANCCR	CAN clock control register	0x00

Table 9. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 50CC	CLK	CLK_HSITRIMR	HSI clock calibration trimming register	0x00
0x00 50CD		CLK_SWIMCCR	SWIM clock control register	0bXXXX XXX0
0x00 50CE to 0x00 50D0	Reserved area (3 bytes)			
0x00 50D1	WWDG	WWDG_CR	WWDG control register	0x7F
0x00 50D2		WWDG_WR	WWDR window register	0x7F
0x00 50D3 to 0x00 50DF	Reserved area (13 bytes)			
0x00 50E0	IWDG	IWDG_KR	IWDG key register	0xXX(2)
0x00 50E1		IWDG_PR	IWDG prescaler register	0x00
0x00 50E2		IWDG_RLR	IWDG reload register	0xFF
0x00 50E3 to 0x00 50EF	Reserved area (13 bytes)			
0x00 50F0	AWU	AWU_CSR1	AWU control/status register 1	0x00
0x00 50F1		AWU_APR	AWU asynchronous prescaler buffer register	0x3F
0x00 50F2		AWU_TBR	AWU timebase selection register	0x00
0x00 50F3	BEEP	BEEP_CSR	BEEP control/status register	0x1F
0x00 50F4 to 0x00 50FF	Reserved area (12 bytes)			
0x00 5200	SPI	SPI_CR1	SPI control register 1	0x00
0x00 5201		SPI_CR2	SPI control register 2	0x00
0x00 5202		SPI_ICR	SPI interrupt control register	0x00
0x00 5203		SPI_SR	SPI status register	0x02
0x00 5204		SPI_DR	SPI data register	0x00
0x00 5205		SPI_CRCPR	SPI CRC polynomial register	0x07
0x00 5206		SPI_RXCRCR	SPI Rx CRC register	0xFF
0x00 5207		SPI_TXCRCR	SPI Tx CRC register	0xFF
0x00 5208 to 0x00 520F	Reserved area (8 bytes)			
0x00 5210	I^2C	I2C_CR1	I^2C control register 1	0x00
0x00 5211		I2C_CR2	I^2C control register 2	0x00
0x00 5212		I2C_FREQR	I^2C frequency register	0x00
0x00 5213		I2C_OARL	I^2C own address register low	0x00
0x00 5214		I2C_OARH	I^2C own address register high	0x00
0x00 5215		Reserved		

Table 9. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5428	beCAN	CAN_P0	CAN paged register 0	0xXX(3)
0x00 5429		CAN_P1	CAN paged register 1	0xXX(3)
0x00 542A		CAN_P2	CAN paged register 2	0xXX(3)
0x00 542B		CAN_P3	CAN paged register 3	0xXX(3)
0x00 542C		CAN_P4	CAN paged register 4	0xXX(3)
0x00 542D		CAN_P5	CAN paged register 5	0xXX(3)
0x00 542E		CAN_P6	CAN paged register 6	0xXX(3)
0x00 542F		CAN_P7	CAN paged register 7	0xXX(3)
0x00 5430		CAN_P8	CAN paged register 8	0xXX(3)
0x00 5431		CAN_P9	CAN paged register 9	0xXX(3)
0x00 5432		CAN_PA	CAN paged register A	0xXX(3)
0x00 5433		CAN_PB	CAN paged register B	0xXX(3)
0x00 5434		CAN_PC	CAN paged register C	0xXX(3)
0x00 5435		CAN_PD	CAN paged register D	0xXX(3)
0x00 5436		CAN_PE	CAN paged register E	0xXX(3)
0x00 5437		CAN_PF	CAN paged register F	0xXX(3)
0x00 5438 to 0x00 57FF	Reserved area (968 bytes)			

1. Depends on the previous reset source.
2. Write only register.
3. If the bootloader is enabled, it is initialized to 0x00.

Table 13. Option byte description (continued)

Option byte no.	Description
OPT3	**LSI_EN:** *Low speed internal clock enable* 0: LSI clock is not available as CPU clock source 1: LSI clock is available as CPU clock source
	IWDG_HW: *Independent watchdog* 0: IWDG Independent watchdog activated by software 1: IWDG Independent watchdog activated by hardware
	WWDG_HW: *Window watchdog activation* 0: WWDG window watchdog activated by software 1: WWDG window watchdog activated by hardware
	WWDG_HALT: *Window watchdog reset on halt* 0: No reset generated on halt if WWDG active 1: Reset generated on halt if WWDG active
OPT4	**EXTCLK:** *External clock selection* 0: External crystal connected to OSCIN/OSCOUT 1: External clock signal on OSCIN
	CKAWUSEL: *Auto wakeup unit/clock* 0: LSI clock source selected for AWU 1: HSE clock with prescaler selected as clock source for AWU
	PRSC[1:0] AWU clock prescaler 00: 24 MHz to 128 kHz prescaler 01: 16 MHz to 128 kHz prescaler 10: 8 MHz to 128 kHz prescaler 11: 4 MHz to 128 kHz prescaler
OPT5	**HSECNT[7:0]:** *HSE crystal oscillator stabilization time* This configures the stabilization time. 0x00: 2048 HSE cycles 0xB4: 128 HSE cycles 0xD2: 8 HSE cycles 0xE1: 0.5 HSE cycles
OPT6	Reserved
OPT7	**WAITSTATE** *Wait state configuration* This option configures the number of wait states inserted when reading from the Flash/data EEPROM memory. 1 wait state is required if f_{CPU} > 16 MHz. 0: No wait state 1: 1 wait state

Total current consumption and timing in forced reset state

Table 29. Total current consumption and timing in forced reset state

Symbol	Parameter	Conditions	Typ	Max(1)	Unit
$I_{DD(R)}$	Supply current in reset state	V_{DD} = 5 V	1.6		mA
		V_{DD} = 3.3 V	0.8		
$t_{RESETBL}$	Reset release to bootloader vector fetch			150	µs

1. Data guaranteed by design, not tested in production.

Current consumption of on-chip peripherals

Subject to general operating conditions for V_{DD} and T_A.

HSI internal RC/f_{CPU} = f_{MASTER} = 16 MHz.

Table 30. Peripheral current consumption

Symbol	Parameter	Typ.	Unit
$I_{DD(TIM1)}$	TIM1 supply current (1)	220	µA
$I_{DD(TIM2)}$	TIM2 supply current (1)	120	
$I_{DD(TIM3)}$	TIM3 timer supply current (1)	100	
$I_{DD(TIM4)}$	TIM4 timer supply current (1)	25	
$I_{DD(UART1)}$	UART1 supply current (2)	90	
$I_{DD(UART3)}$	UART3 supply current (2)	110	
$I_{DD(SPI)}$	SPI supply current (2)	40	
$I_{DD(I^2C)}$	I^2C supply current (2)	50	
$I_{DD(CAN)}$	beCAN supply current (2)	210	
$I_{DD(ADC2)}$	ADC2 supply current when converting (3)	1000	

1. Data based on a differential I_{DD} measurement between reset configuration and timer counter running at 16 MHz. No IC/OC programmed (no I/O pads toggling). Not tested in production.
2. Data based on a differential I_{DD} measurement between the on-chip peripheral when kept under reset and not clocked and the on-chip peripheral when clocked and not kept under reset. No I/O pads toggling. Not tested in production.
3. Data based on a differential I_{DD} measurement between reset configuration and continuous A/D conversions. Not tested in production.

Current consumption curves

Figure 14 and *Figure 15* show typical current consumption measured with code executing in RAM.

Figure 14. Typ. $I_{DD(RUN)}$ vs V_{DD}, HSI RC osc, f_{CPU} = 16 MHz

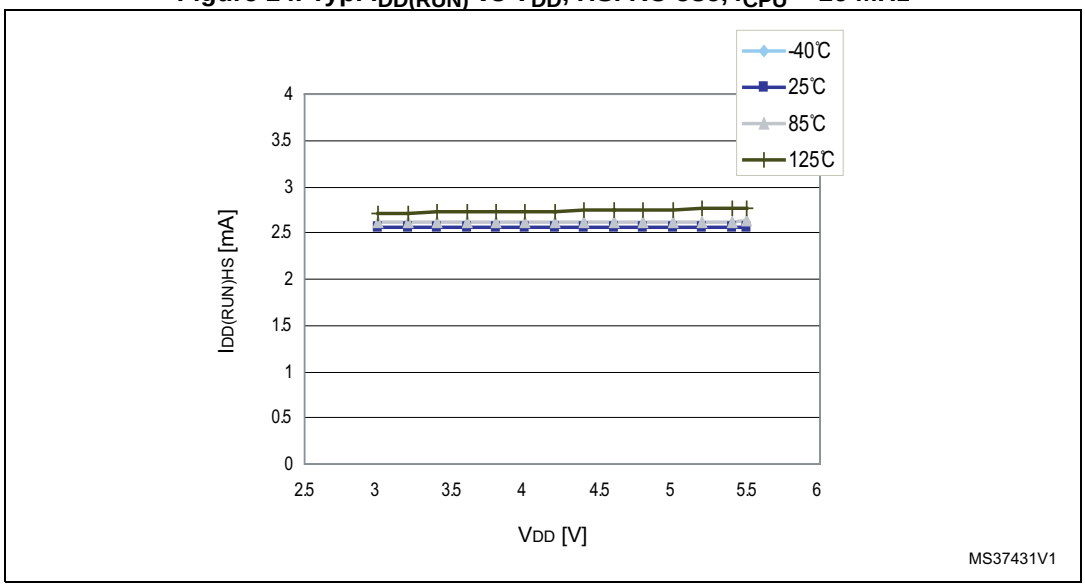
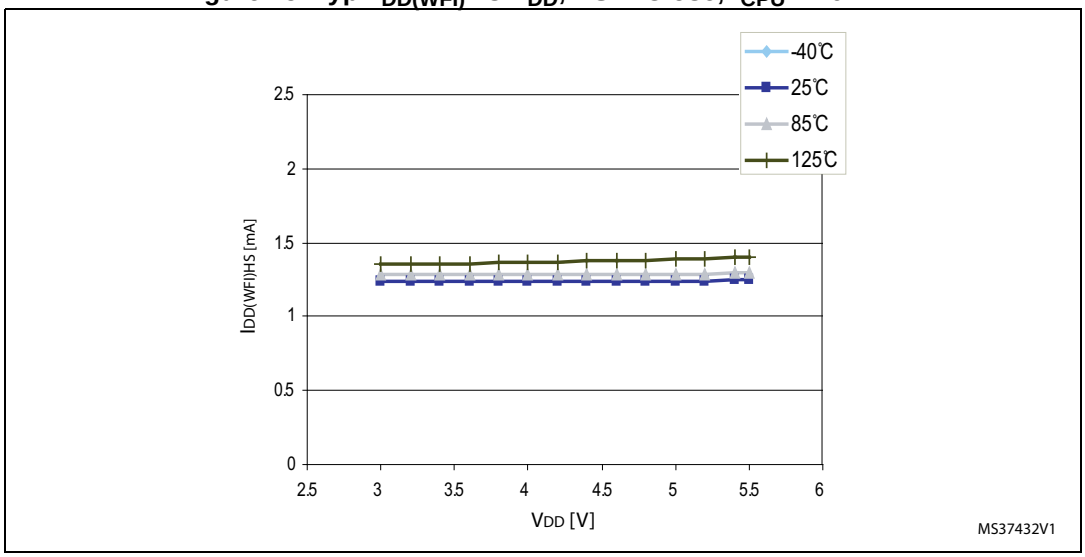


Figure 15. Typ. $I_{DD(WFI)}$ vs V_{DD}, HSI RC osc, f_{CPU} = 16 MHz



10.3.3 External clock sources and timing characteristics

HSE user external clock

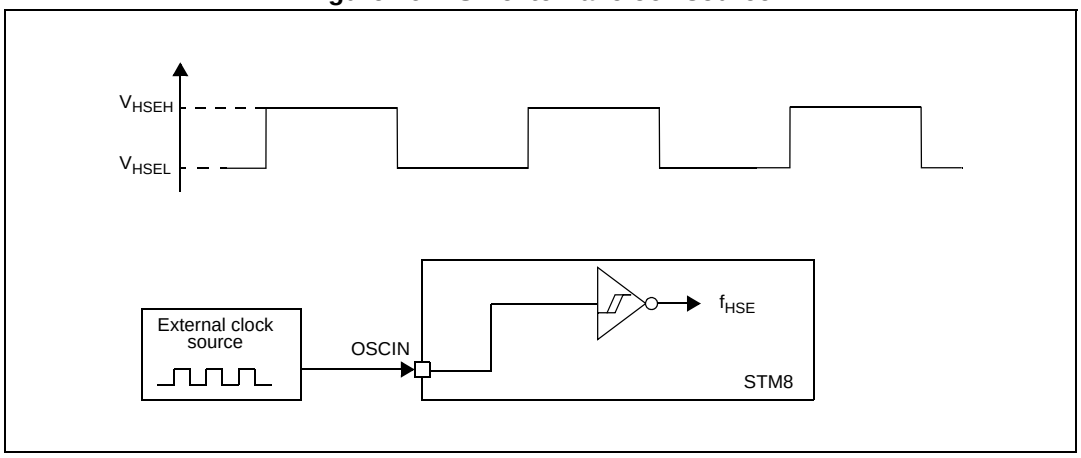
Subject to general operating conditions for V_{DD} and T_A.

Table 31. HSE user external clock characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{HSE_ext}	User external clock source frequency		0		24	MHz
V_{HSEH}(1)	OSCIN input pin high level voltage		0.7 x V_{DD}		V_{DD} + 0.3 V	V
V_{HSEL}(1)	OSCIN input pin low level voltage		V_{SS}		0.3 x V_{DD}	
I_{LEAK_HSE}	OSCIN input leakage current	$V_{SS} < V_{IN} < V_{DD}$	-1		1	µA

1. Data based on characterization results, not tested in production.

Figure 16. HSE external clock source



HSE crystal/ceramic resonator oscillator

The HSE clock can be supplied with a 1 to 24 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph is based on characterization results with specified typical external components. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and start-up stabilization time. Refer to the crystal resonator manufacturer for more details (frequency, package, accuracy...).

10.3.4 Internal clock sources and timing characteristics

Subject to general operating conditions for V_{DD} and T_A. f_{HSE}

High speed internal RC oscillator (HSI)

Table 33. HSI oscillator characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{HSI}	Frequency			16		MHz
ACC_{HSI}	Accuracy of HSI oscillator	Trimmed by the CLK_HSITRIMR register for given V_{DD} and T_A conditions	-1.0(1)		1.0	%
	Accuracy of HSI oscillator (factory calibrated)	V_{DD} = 5 V, T_A = 25 °C	-1.5		1.5	
		V_{DD} = 5 V, 25 °C ≤ T_A ≤ 85 °C	-2.2		2.2	
		2.95 V ≤ V_{DD} ≤ 5.5 V, -40 °C ≤ T_A ≤ 125 °C	-3.0(2)		3.0(2)	
$t_{su(HSI)}$	HSI oscillator wakeup time including calibration				1.0(1)	µs
$I_{DD(HSI)}$	HSI oscillator power consumption			170	250(2)	µA

1. Guaranteed by design, not tested in production.
2. Data based on characterization results, not tested in production

Figure 18. Typical HSI frequency variation vs V_{DD} at 4 temperatures

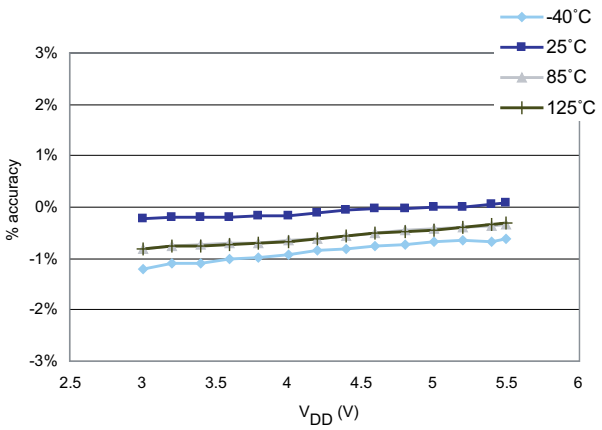
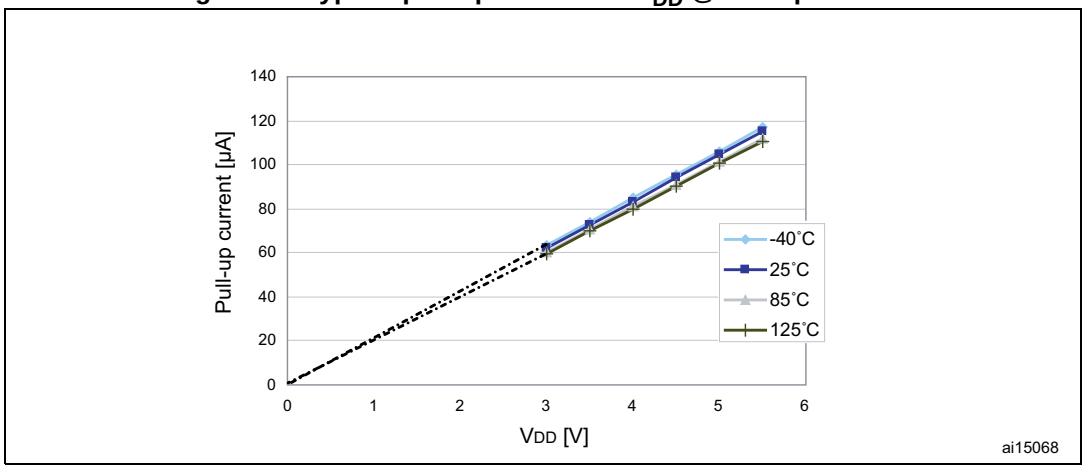


Figure 22. Typical pull-up current vs V_{DD} @ 4 temperatures



1. The pull-up is a pure resistor (slope goes through 0).

Table 38. Output driving current (standard ports)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level with 8 pins sunk	I_{IO} = 10 mA, V_{DD} = 5 V		2	V
	Output low level with 4 pins sunk	I_{IO} = 4 mA, V_{DD} = 3.3 V		1(1)	
V_{OH}	Output high level with 8 pins sourced	I_{IO} = 10 mA, V_{DD} = 5 V	2.8		V
	Output high level with 4 pins sourced	I_{IO} = 4 mA, V_{DD} = 3.3 V	2.1(1)		

1. Data based on characterization results, not tested in production

Table 39. Output driving current (true open drain ports)

Symbol	Parameter	Conditions	Max	Unit
V_{OL}	Output low level with 2 pins sunk	I_{IO} = 10 mA, V_{DD} = 5 V	1	V
		I_{IO} = 10 mA, V_{DD} = 3.3 V	1.5(1)	
		I_{IO} = 20 mA, V_{DD} = 5 V	2(1)	

1. Data based on characterization results, not tested in production

Table 40. Output driving current (high sink ports)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level with 8 pins sunk	I_{IO} = 10 mA, V_{DD} = 5 V		0.8	V
	Output low level with 4 pins sunk	I_{IO} = 10 mA, V_{DD} = 3.3 V		1(1)	
	Output low level with 4 pins sunk	I_{IO} = 20 mA, V_{DD} = 5 V		1.5(1)	
V_{OH}	Output high level with 8 pins sourced	I_{IO} = 10 mA, V_{DD} = 5 V	4.0		
	Output high level with 4 pins sourced	I_{IO} = 10 mA, V_{DD} = 3.3 V	2.1(1)		
	Output high level with 4 pins sourced	I_{IO} = 20 mA, V_{DD} = 5 V	3.3(1)		

1. Data based on characterization results, not tested in production

10.3.7 Reset pin characteristics

Subject to general operating conditions for V_{DD} and T_A unless otherwise specified.

Table 41. NRST pin characteristics

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
$V_{IL(NRST)}$	NRST Input low level voltage (1)		-0.3 V		0.3 x V_{DD}	V
$V_{IH(NRST)}$	NRST Input high level voltage (1)		0.7 x V_{DD}		V_{DD} + 0.3	
$V_{OL(NRST)}$	NRST Output low level voltage (1)	I_{OL}= 2 mA			0.5	
$R_{PU(NRST)}$	NRST Pull-up resistor (2)		30	55	80	kΩ
$t_{IFP(NRST)}$	NRST Input filtered pulse (3)				75	ns
$t_{INFP(NRST)}$	NRST Input not filtered pulse (3)		500			ns
$t_{OP(NRST)}$	NRST output pulse (1)		15			µs

1. Data based on characterization results, not tested in production.
2. The R_{PU} pull-up equivalent resistor is based on a resistive transistor
3. Data guaranteed by design, not tested in production.

Figure 33. Typical NRST V_{IL} and V_{IH} vs V_{DD} @ 4 temperatures

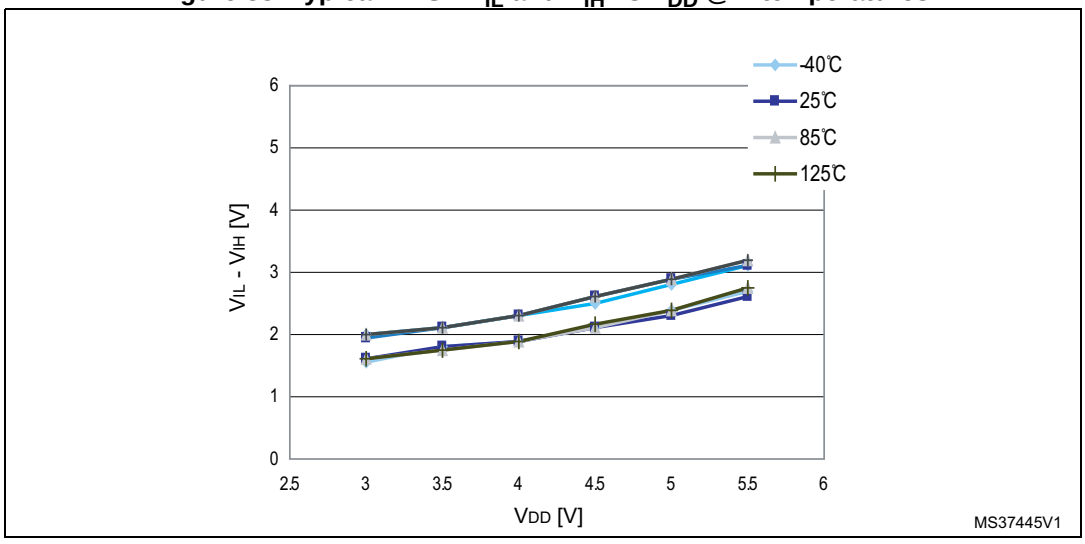
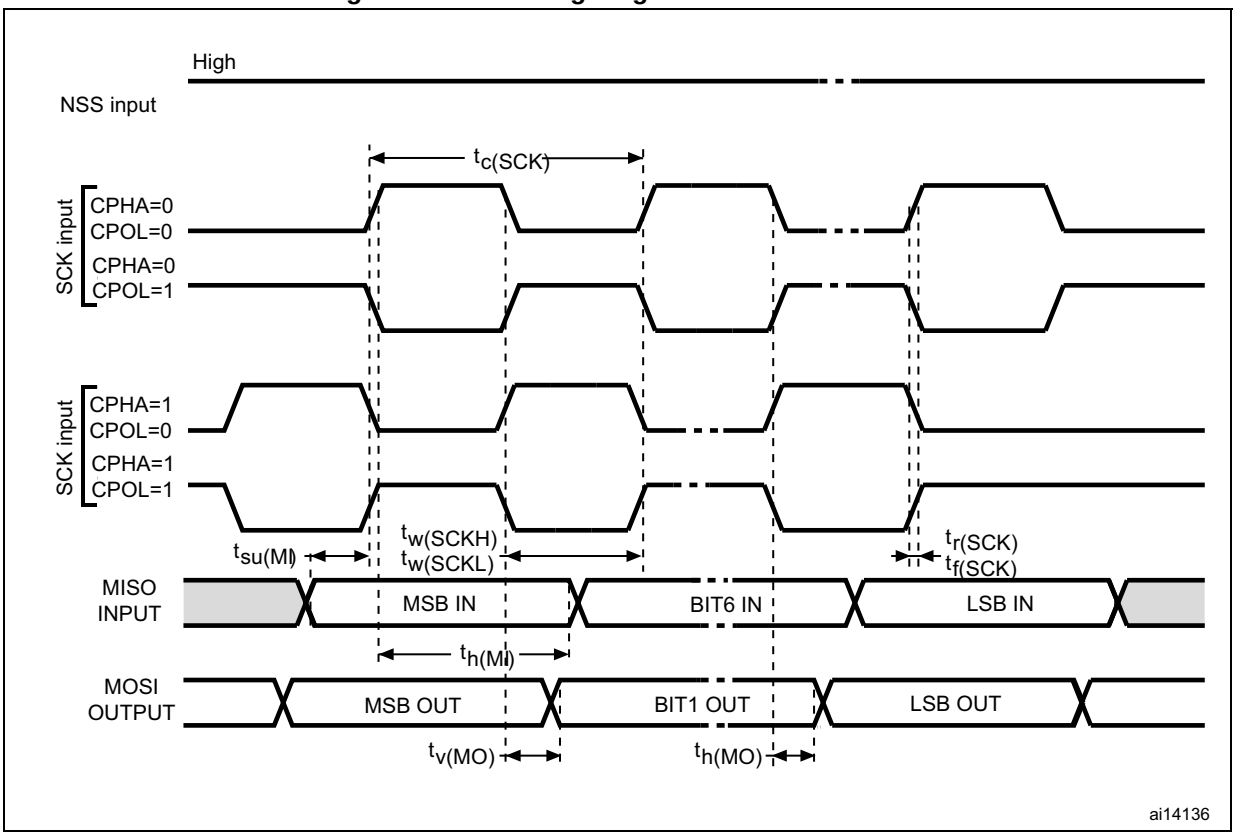
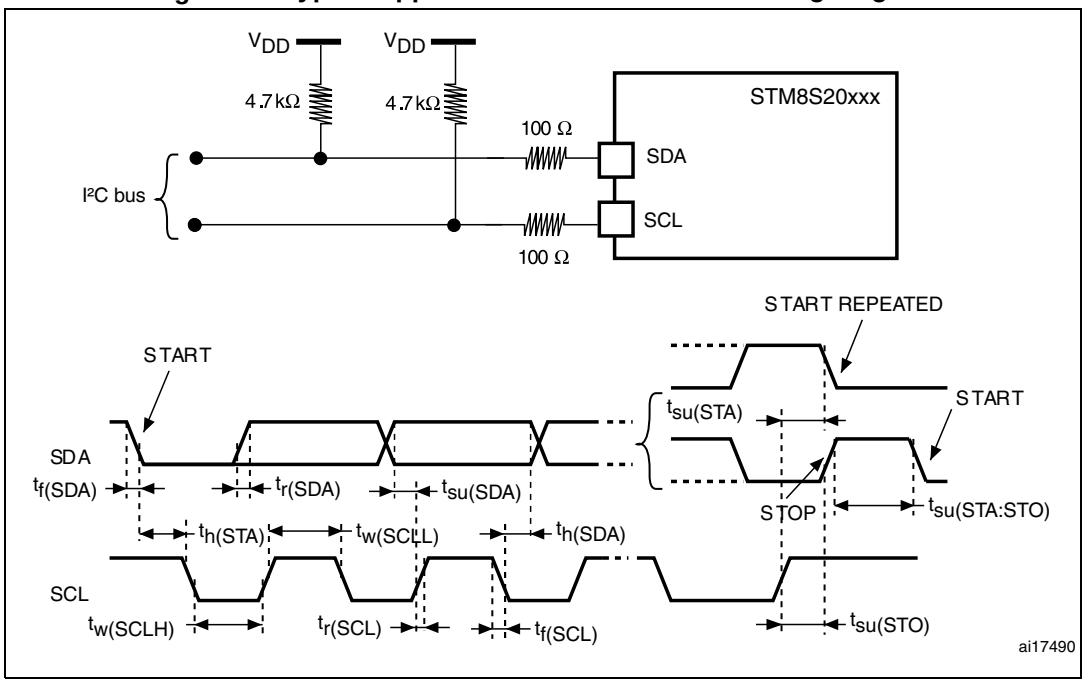


Figure 39. SPI timing diagram - master mode(1)



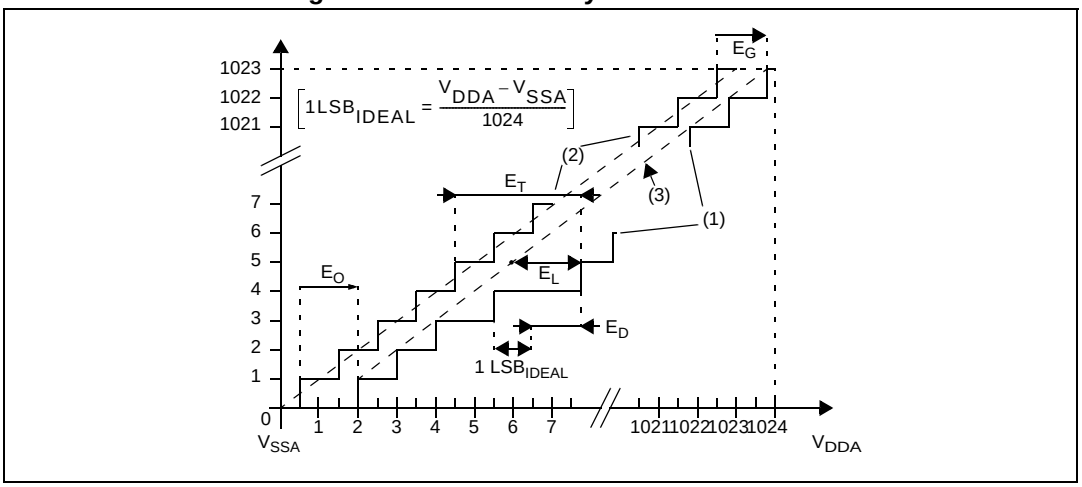
1. Measurement points are done at CMOS levels: 0.3 V_{DD} and 0.7 V_{DD}.

Figure 40. Typical application with I²C bus and timing diagram



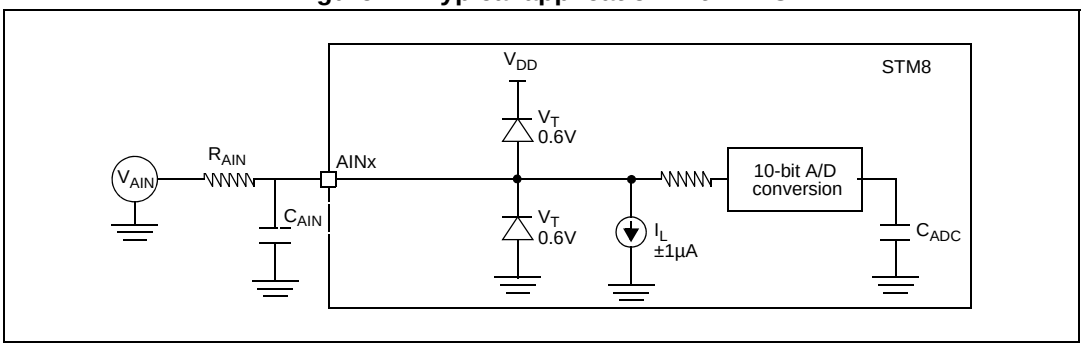
1. Measurement points are made at CMOS levels: 0.3 x V_{DD} and 0.7 x V_{DD}

Figure 41. ADC accuracy characteristics



1. Example of an actual transfer curve.
2. The ideal transfer curve
3. End point correlation line
   E_T = Total unadjusted error: maximum deviation between the actual and the ideal transfer curves.
   E_O = Offset error: deviation between the first actual transition and the first ideal one.
   E_G = Gain error: deviation between the last ideal transition and the last actual one.
   E_D = Differential linearity error: maximum deviation between actual steps and the ideal one.
   E_L = Integral linearity error: maximum deviation between any actual transition and the end point correlation line.

Figure 42. Typical application with ADC



Static latch-up

Two complementary static tests are required on 10 parts to assess the latch-up performance:

- A supply overvoltage (applied to each power supply pin)
- A current injection (applied to each input, output and configurable I/O pin) is performed on each sample.

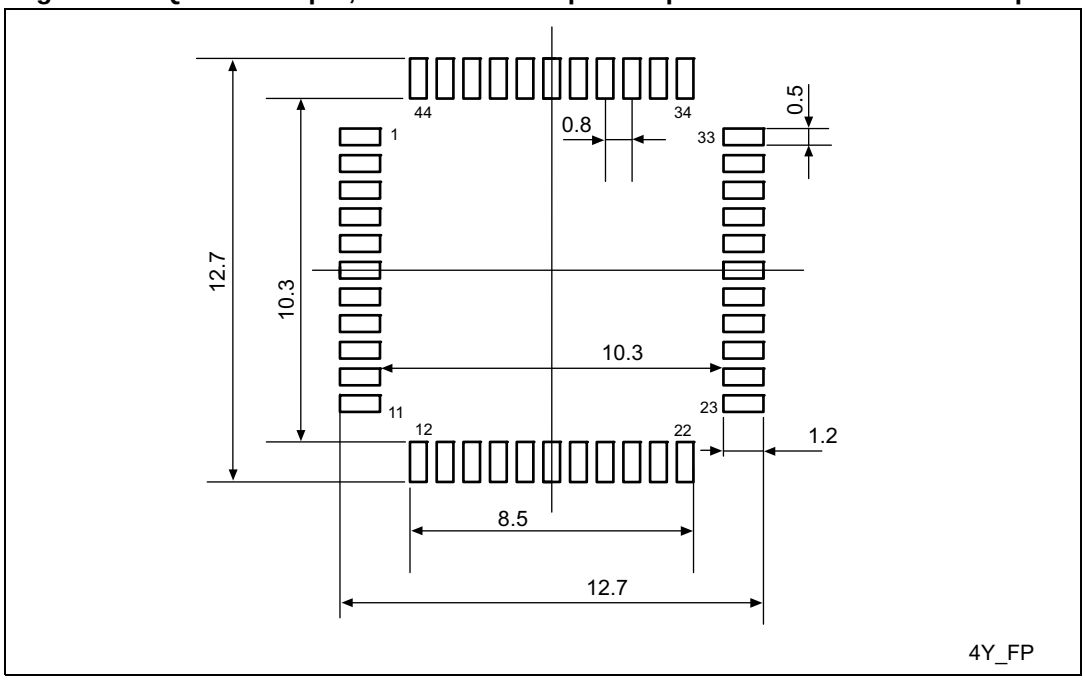
This test conforms to the EIA/JESD 78 IC latch-up standard. For more details, refer to the application note AN1181.

Table 50. Electrical sensitivities

Symbol	Parameter	Conditions	Class(1)
LU	Static latch-up class	$T_A = 25$ °C	A
		$T_A = 85$ °C	A
		$T_A = 125$ °C	A

1. Class description: A Class is an STMicroelectronics internal specification. All its limits are higher than the JEDEC specifications, that means when a device belongs to class A it exceeds the JEDEC standard. B class strictly covers all the JEDEC criteria (international standard).

Figure 54. LQFP44 - 44-pin, 10 x 10 mm low-profile quad flat recommended footprint

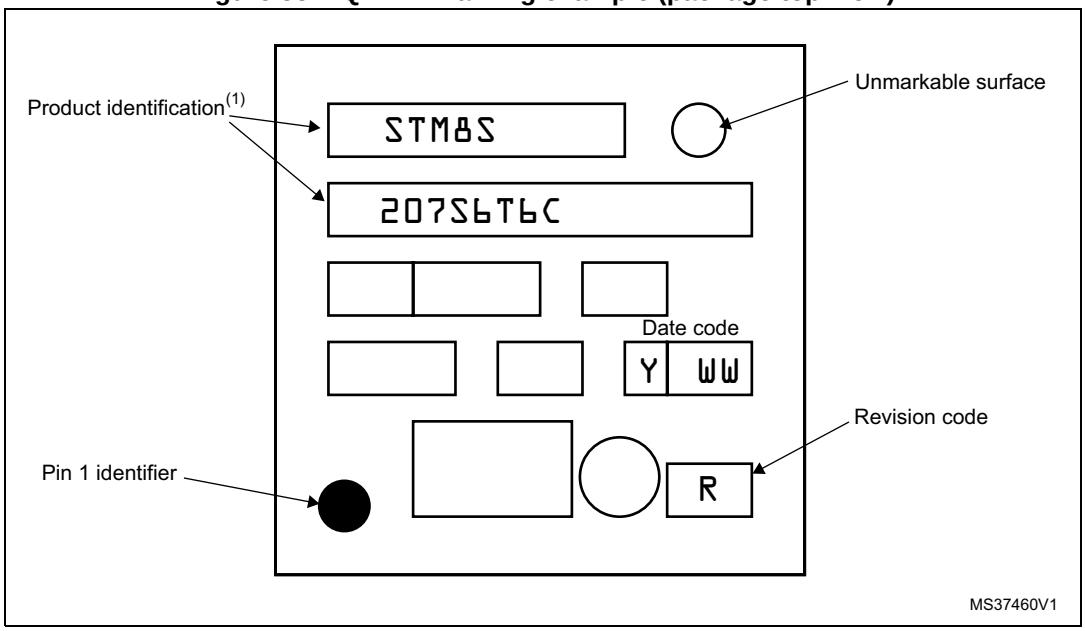


1. Dimensions are expressed in millimeters.

Device marking

The following figure shows the marking for the LQFP44 package.

Figure 55. LQFP44 marking example (package top view)

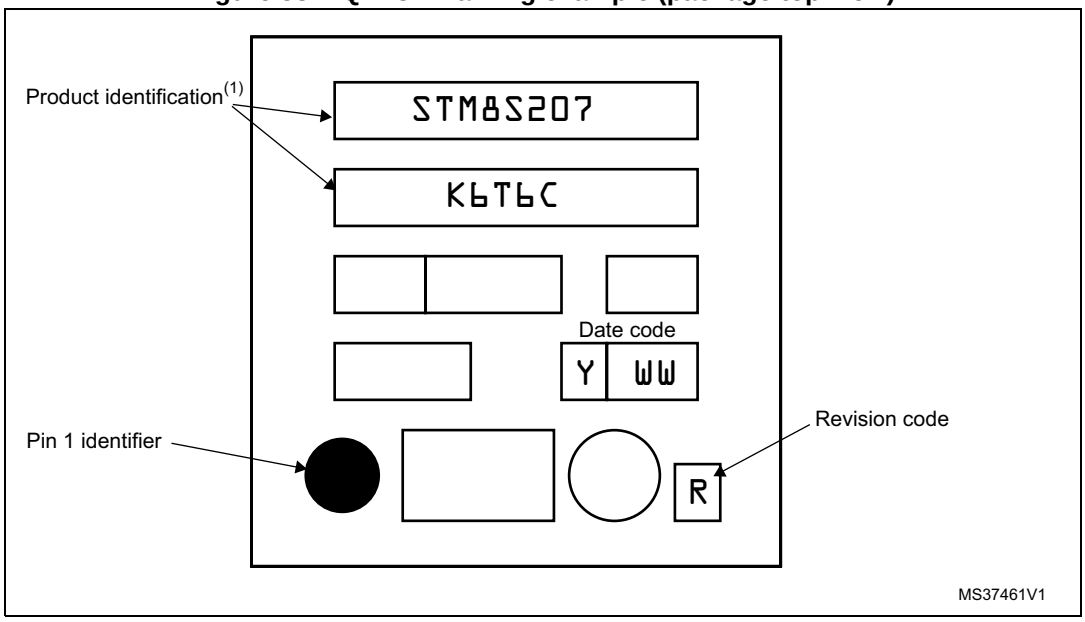


1. Parts marked as “ES”,”E” or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

Device marking

The following figure shows the marking for the LQFP32 package.

Figure 58. LQFP32 marking example (package top view)



1. Parts marked as “ES”,”E” or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

11.2 Thermal characteristics

The maximum chip junction temperature (T_{Jmax}) must never exceed the values given in *Table 18: General operating conditions on page 56*.

The maximum chip-junction temperature, T_{Jmax}, in degrees Celsius, may be calculated using the following equation:

$T_{Jmax} = T_{Amax} + (P_{Dmax} \times \Theta_{JA})$

Where:

- T_{Amax} is the maximum ambient temperature in °C
- Θ_{JA} is the package junction-to-ambient thermal resistance in ° C/W
- P_{Dmax} is the sum of P_{INTmax} and $P_{I/Omax}$ ($P_{Dmax} = P_{INTmax} + P_{I/Omax}$)
- P_{INTmax} is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.
- $P_{I/Omax}$ represents the maximum power dissipation on output pins, where: $P_{I/Omax} = \Sigma (V_{OL}*I_{OL}) + \Sigma((V_{DD}-V_{OH})*I_{OH})$, and taking account of the actual V_{OL}/I_{OL} and V_{OH}/I_{OH} of the I/Os at low and high level in the application.

Table 57. Thermal characteristics(1)

Symbol	Parameter	Value	Unit
Θ_{JA}	Thermal resistance junction-ambient LQFP 80 - 14 x 14 mm	38	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 64 - 14 x 14 mm	45	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 64 - 10 x 10 mm	46	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 48 - 7 x 7 mm	57	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 44 - 10 x 10 mm	54	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 32 - 7 x 7 mm	60	°C/W

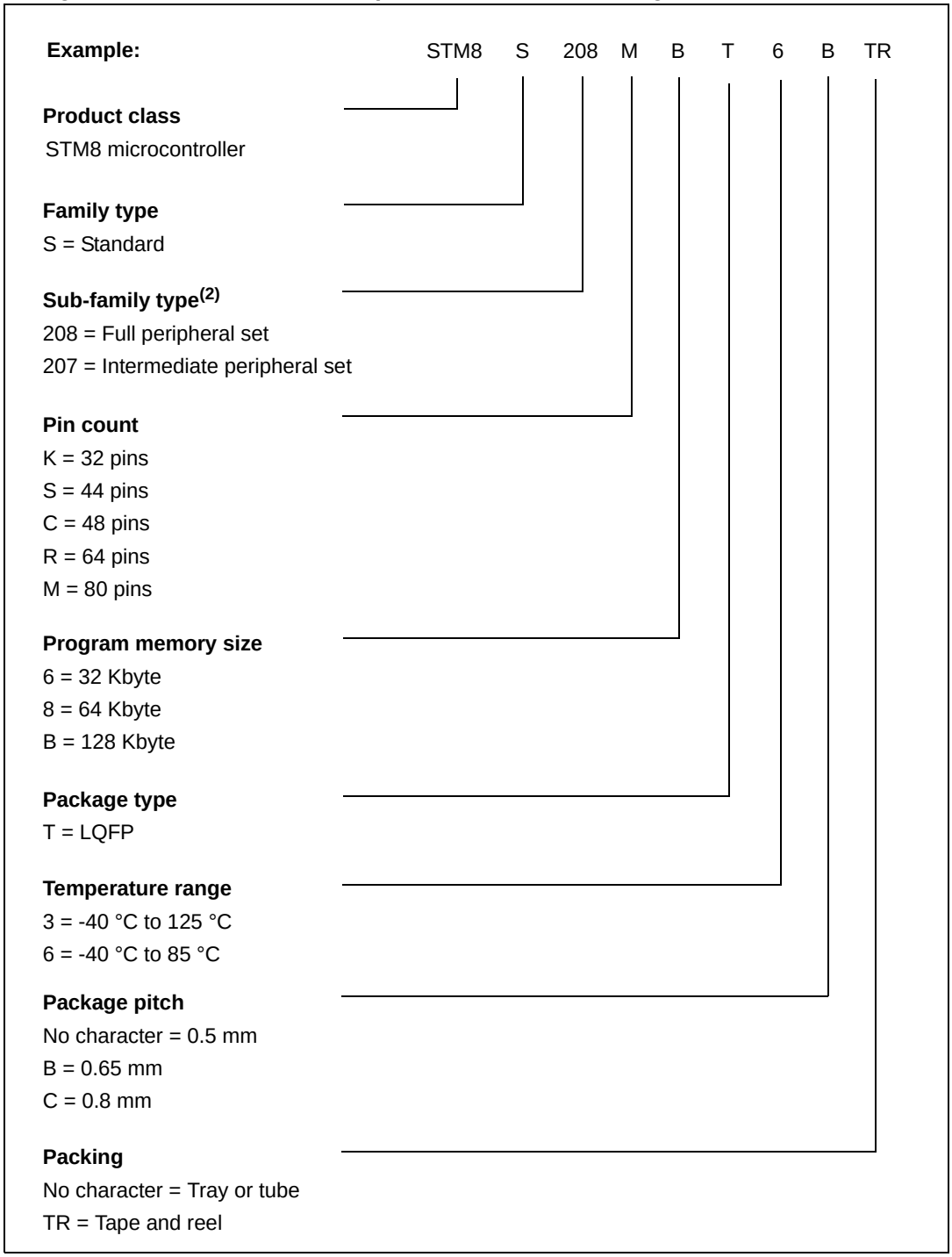
1. Thermal resistances are based on JEDEC JESD51-2 with 4-layer PCB in a natural convection environment.

11.2.1 Reference document

JESD51-2 integrated circuits thermal test method environment conditions - natural convection (still air). Available from www.jedec.org.

13 Ordering information

Figure 59. STM8S207xx/208xx performance line ordering information scheme(1)



1. For a list of available options (e.g. memory size, package) and order-able part numbers or for further information on any aspect of this device, please go to *www.st.com* or contact the ST Sales Office nearest to you.
2. Refer to *Table 2: STM8S20xxx performance line features* for detailed description.